

The effect of nano-sized starting materials and excess amount of Bi on the dielectric/piezoelectric properties of $0.94[(\text{Bi}_x\text{Na}_{0.5})\text{TiO}_3]-0.06[\text{BaTiO}_3]$ lead free piezoelectric ceramics

Neamul Hayet Khansur, Soon-Chul Ur, Man-Soon Yoon[†]

Dept. of Materials Sci. and Eng., Research center for Sustainable Eco-Devices and Materials (ReSEM), Chungju National University, Chungbuk, 380-702, Republic of Korea.
(msyoon@cjnu.ac.kr[†])

In an approach to acclimate ourselves to recent ecological consciousness trend, a lead-free piezoelectric material, bismuth sodium titanate (abbreviated as BNT) based bismuth sodium barium titanate (abbreviated as BNT-BT), was considered as an environment-friendly alternative for a lead based piezoelectric system. Ceramic specimens of $0.94[(\text{Bi}_x\text{Na}_{0.5})\text{TiO}_3]-0.06[\text{BaTiO}_3]$ ($x = 0.500\sim 0.515$) compositions were prepared by a modified mixed oxide method. To increase the chemical homogeneity and reaction activity, high energy mechanical milling machine and pre-milled nanosized powder has been used. In this method $(\text{Bi}_x\text{Na}_{0.5})\text{TiO}_3$ ($x=0.500\sim 0.515$) and BaTiO_3 were prepared separately from pre-milled constituent materials at low calcination temperature and then separately prepared BNTX ($X=1, 2, 3$ and 4) and BT were mixed by high energy mechanical milling machine. Without further calcination step the mixed powders were pressed into disk shape and sintered at 1110°C . Microstructures, phase structures and electrical properties of the ceramic specimens were systematically investigated. Highly dense ceramic specimens with homogenous grains were prepared in spite of relatively low sintering temperature. Phase structures were not significantly influenced by the excess amount Bi. Large variation on the piezoelectric and dielectric properties was detected at relative high excess Bi amounts. When $x \leq 0.505$, the specimens exhibit insignificant variation in piezoelectric and dielectric constant though depolarization temperature is found to be decreased. Considerable amount of decrease in piezoelectric and dielectric properties are observed with higher excess of Bi amounts ($x \geq 0.505$). This research indicates the advantages of high energy mechanical milling and importance of proper maintenance of Bi stoichiometry.

Keywords: High energy mechanical milling, BNT-BT, Excess Bismuth

물리적, 화학적 방법으로 환원된 그래핀의 분자구조

Ju HyeMi[†], Choi SeongHo^{*}, Cho KwangYeon^{*}, Kim ChangYeoul^{*}, Hyun Sangil^{*},
Huh SeungHun^{*}, Lee HongLim^{**}

Korea Institute of Ceramic Engineering and Technology, Yonsei University, Advanced Materials Engineering;
^{*}Korea Institute of Ceramic Engineering and Technology; ^{**}Yonsei University, Advanced Materials Engineering
(juhemlove@hanmail.net[†])

본 연구에서는 Graphene oxide를 800°C , 질소분위기 하에서 환원시켜 얻은 GP_{TR} 과 Hydrazine을 이용한 화학적 처리로 얻은 GP_{CR} 의 분자구조를 제안하였다. 이때 graphene oxide는 modified Hummers' method를 이용하여 제조하였다. GP_{TR} 과 GP_{CR} 은 모두 표면에 몇몇의 oxide group이 존재하는데 GP_{TR} 은 six layer로 $\text{C}_{100}\text{O}_{3\pm 1}$ 의 조성을 갖고 GP_{CR} 은 three layer로 and $\text{C}_{100}\text{O}_{6.5\pm 2}$ 의 조성을 갖는다. 그리고 면간간격은 GP_{TR} 은 3.432 \AA , GP_{CR} 은 3.760 \AA 으로 전형적인 방법인 top down process로 얻은 graphene 보다 다소 크다는 것을 알 수 있다.

Keywords: graphene